STB30N65M5, STF30N65M5, STI30N65M5
STP30N65M5, STW30N65M5

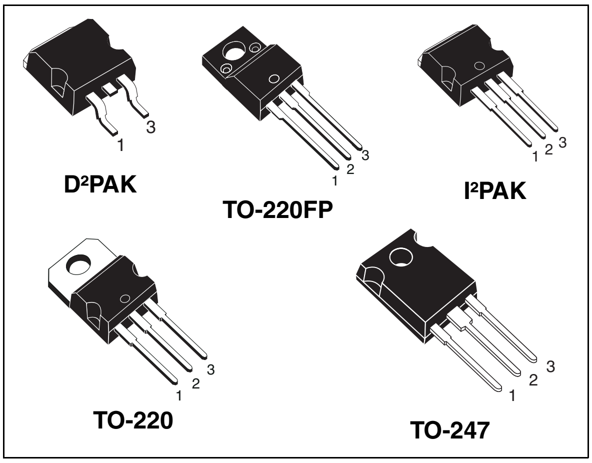
N-channel 650 V, 0.125 Ω, 22 A, MDmesh™ V Power MOSFET D²PAK, TO-220FP, I²PAK, TO-220, TO-247

Features

Order codes	V_{DSS} @ T_{JMAX}	$R_{DS(on)}$ max.	I_D
STB30N65M5	710 V	< 0.139 Ω	22 A
STF30N65M5	710 V	< 0.139 Ω	22 A(1)
STI30N65M5	710 V	< 0.139 Ω	22 A
STP30N65M5	710 V	< 0.139 Ω	22 A
STW30N65M5	710 V	< 0.139 Ω	22 A

1. Limited only by maximum temperature allowed

- Worldwide best $R_{DS(on)}$*area
- Higher V_{DSS} rating
- Excellent switching performance
- Easy to drive
- 100% avalanche tested
- High dv/dt capability



Applications

- Switching applications

Description

These devices are N-channel MDmesh™ V Power MOSFETs based on an innovative proprietary vertical process technology, which is combined with STMicroelectronics' well-known PowerMESH™ horizontal layout structure. The resulting product has extremely low on-resistance, which is unmatched among silicon-based Power MOSFETs, making it especially suitable for applications which require superior power density and outstanding efficiency.

Figure 1. Internal schematic diagram

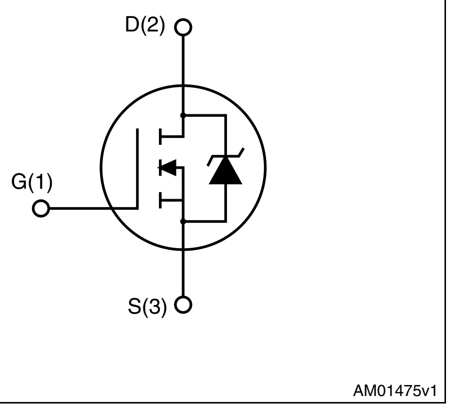


Table 1. Device summary

Order codes	Marking	Package	Packaging
STB30N65M5	30N65M5	D²PAK	Tape and reel
STF30N65M5	30N65M5	TO-220FP	Tube
STI30N65M5	30N65M5	I²PAK	Tube
STP30N65M5	30N65M5	TO-220	Tube
STW30N65M5	30N65M5	TO-247	Tube

Contents

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		TO-220, D²PAK TO-247, I²PAK	TO-220FP	
V_{GS}	Gate-source voltage	± 25		V
I_D	Drain current (continuous) at T_C = 25 °C	22	22 (1)	A
I_D	Drain current (continuous) at T_C = 100 °C	13	13(1)	A
I_{DM} (2)	Drain current (pulsed)	88	88 (1)	A
P_{TOT}	Total dissipation at T_C = 25 °C	140	30	W
I_{AR}	Max current during repetitive or single pulse avalanche (pulse width limited by T_{JMAX})	7		A
E_{AS}	Single pulse avalanche energy (starting T_j = 25°C, I_D = I_{AR}, V_{DD} = 50V)	500		mJ
dv/dt (3)	Peak diode recovery voltage slope	15		V/ns
V_{ISO}	Insulation withstand voltage (RMS) from all three leads to external heat sink (t=1 s;T_C=25 °C)		2500	V
T_{stg}	Storage temperature	- 55 to 150		°C
T_j	Max. operating junction temperature	150		°C

1. Limited only by maximum temperature allowed
2. Pulse width limited by safe operating area
3. I_{SD} ≤ 21 A, di/dt = 400 A/µs, V_{Peak} < $V_{(BR)DSS}$

Table 3. Thermal data

Symbol	Parameter	Value					Unit
		D²PAK	TO-220FP	I²PAK	TO-220	TO-247	
$R_{thj-case}$	Thermal resistance junction-case max	0.83	3.6	0.83			°C/W
$R_{thj-amb}$	Thermal resistance junction-ambient max		62.5			50	°C/W
$R_{thj-pcb}$	Thermal resistance junction-pcb max	30					°C/W
T_l	Maximum lead temperature for soldering purpose		300				°C

2 Electrical characteristics

(T_C = 25 °C unless otherwise specified)

Table 4. On /off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage (V_{GS} = 0)	I_D = 1 mA	650			V
I_{DSS}	Zero gate voltage drain current (V_{GS} = 0)	V_{DS} = 650 V V_{DS} = 650 V, T_C=125 °C			1 100	µA µA
I_{GSS}	Gate-body leakage current (V_{DS} = 0)	V_{GS} = ± 25 V			100	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS} = V_{GS}, I_D = 250 µA	3	4	5	V
$R_{DS(on)}$	Static drain-source on resistance	V_{GS} = 10 V, I_D = 11 A		0.125	0.139	Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V_{DS} = 100 V, f = 1 MHz, V_{GS} = 0	-	2880 68 5	-	pF pF pF
$C_{o(tr)}$(1)	Equivalent capacitance time related	V_{GS} = 0, V_{DS} = 0 to 520 V	-	190	-	pF
$C_{o(er)}$(2)	Equivalent capacitance energy related	V_{GS} = 0, V_{DS} = 0 to 520 V	-	65	-	pF
R_G	Intrinsic gate resistance	f = 1 MHz open drain	-	1.6	-	Ω
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 520 V, I_D = 11 A, V_{GS} = 10 V (see *Figure 20*)	-	64 16 25	-	nC nC nC

1. $C_{oss\ eq.}$ time related is defined as a constant equivalent capacitance giving the same charging time as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}
2. $C_{oss\ eq.}$ energy related is defined as a constant equivalent capacitance giving the same stored energy as C_{oss} when V_{DS} increases from 0 to 80% V_{DSS}

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max	Unit
$t_{d(off)}$ t_r t_c t_f	Turn-off delay time Rise time Cross time Fall time	V_{DD} = 400 V, I_D = 14 A, R_G = 4.7 Ω, V_{GS} = 10 V (see *Figure 21*)	-	50 8 20 10	-	ns ns ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} I_{SDM} (1)	Source-drain current Source-drain current (pulsed)		-		22 88	A A
V_{SD} (2)	Forward on voltage	I_{SD} = 22 A, V_{GS} = 0	-		1.5	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 22 A, di/dt = 100 A/µs V_{DD} = 60 V (see *Figure 21*)	-	336 6 32		ns µC A
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 22 A, di/dt = 100 A/µs V_{DD} = 60 V, T_j = 150 °C (see *Figure 21*)	-	395 7 34		ns µC A

1. Pulse width limited by safe operating area
2. Pulsed: Pulse duration = 300 µs, duty cycle 1.5%

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area for TO-220, D²PAK, I²PAK

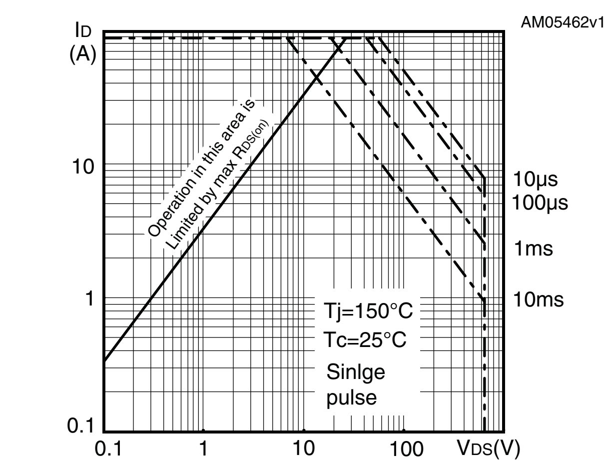


Figure 3. Thermal impedance for TO-220, D²PAK, I²PAK

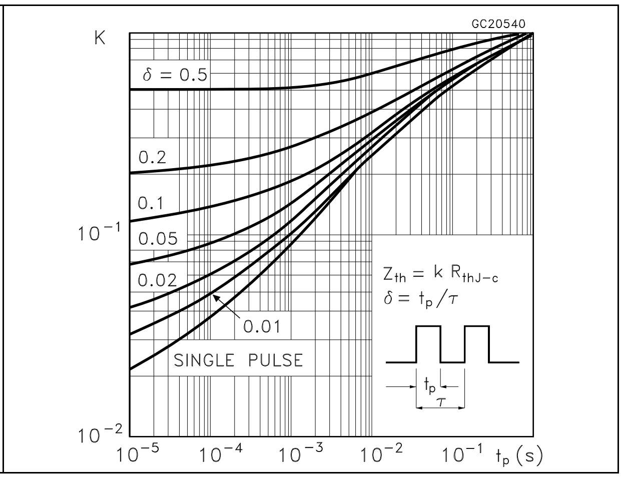


Figure 4. Safe operating area for TO-220FP

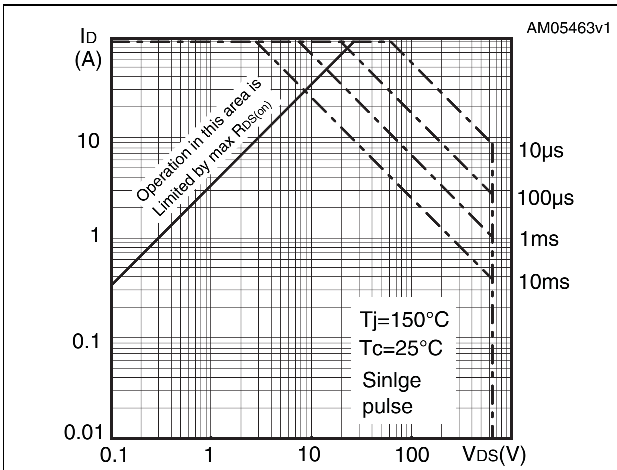


Figure 5. Thermal impedance for TO-220FP

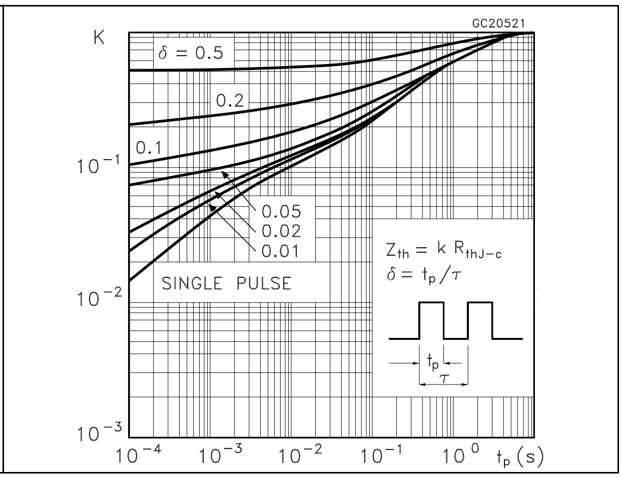


Figure 6. Safe operating area for TO-247

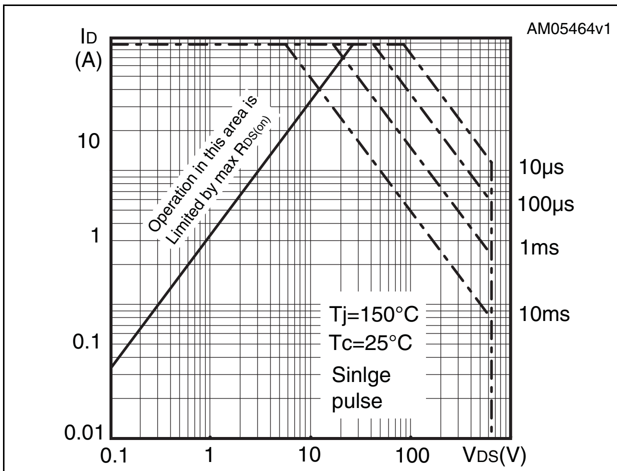


Figure 7. Thermal impedance for TO-247

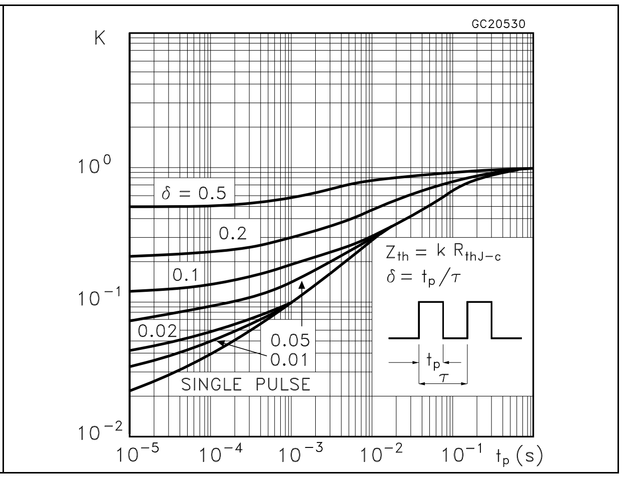


Figure 8. Output characteristics

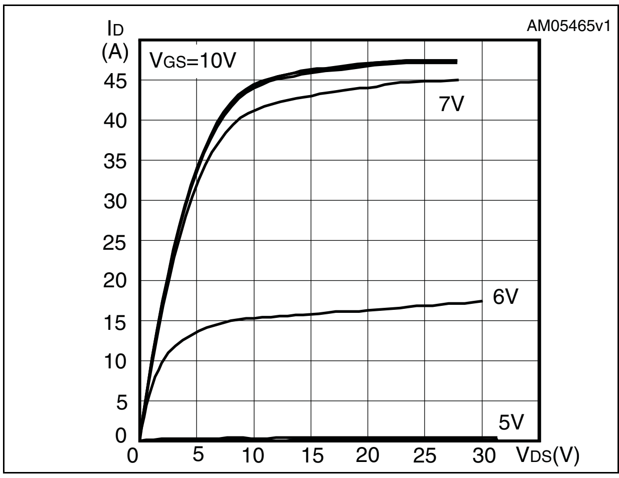


Figure 9. Transfer characteristics

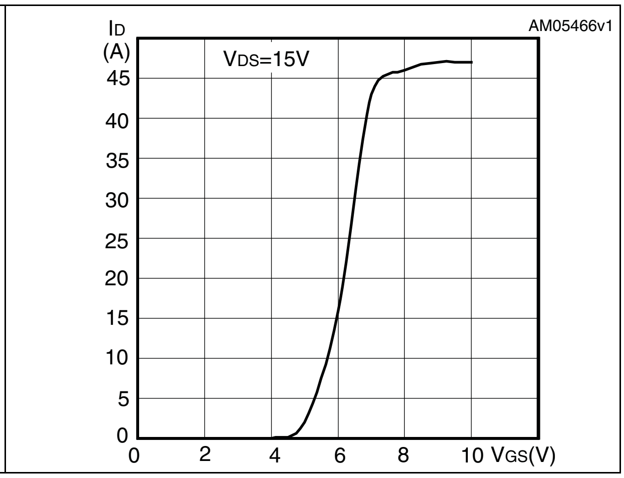


Figure 10. Gate charge vs gate-source voltage

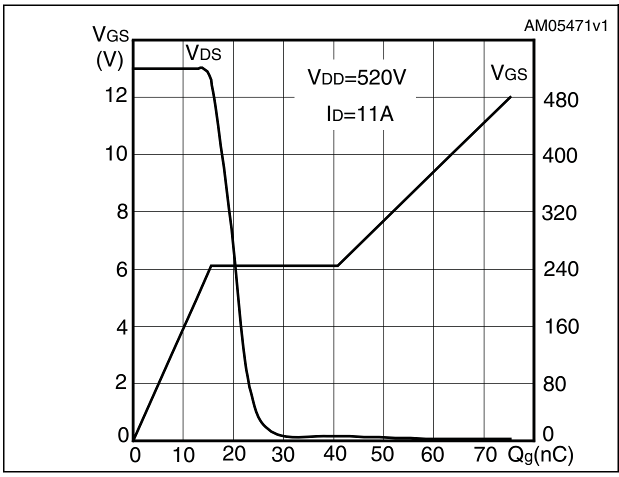


Figure 11. Static drain-source on resistance

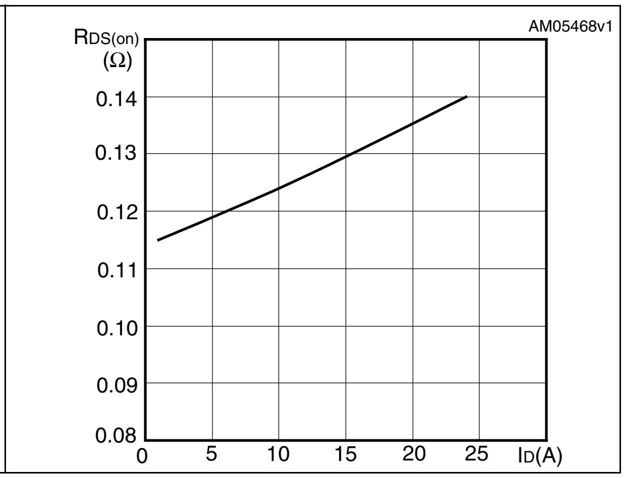


Figure 12. Capacitance variations

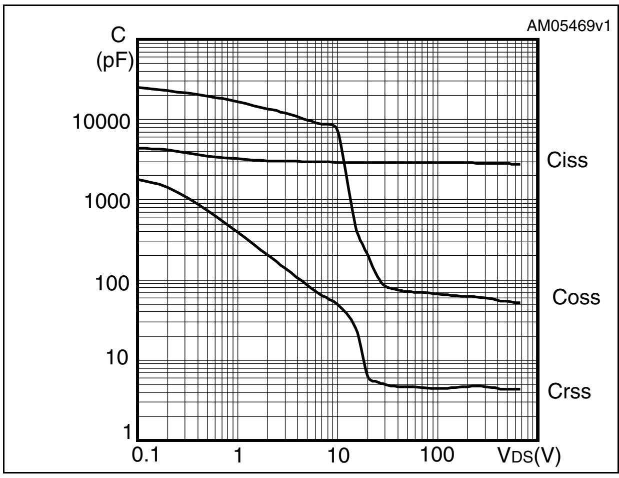


Figure 13. Output capacitance stored energy

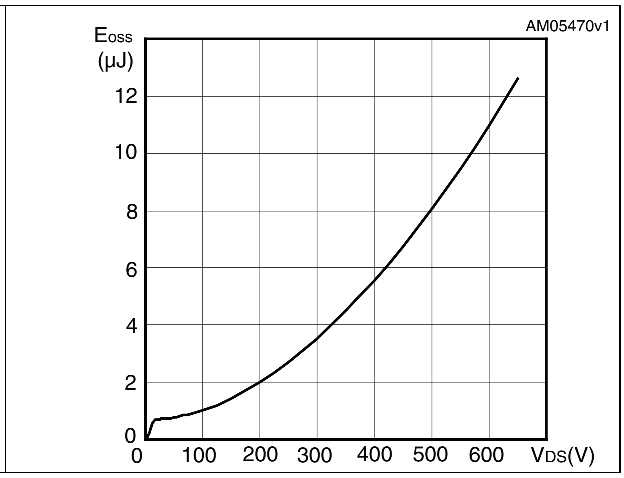


Figure 14. Normalized gate threshold voltage vs temperature

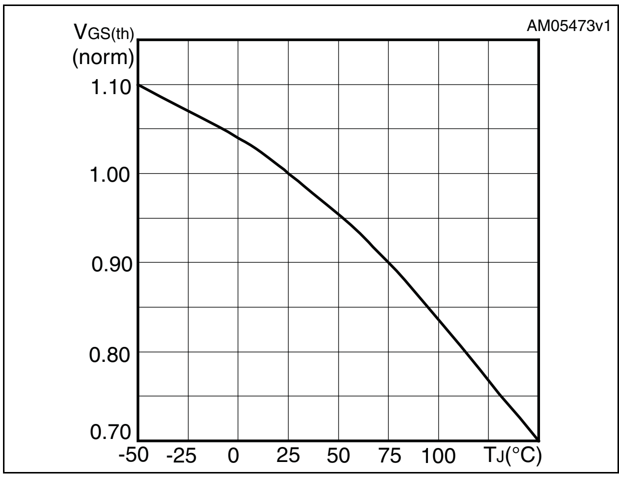


Figure 15. Normalized on resistance vs temperature

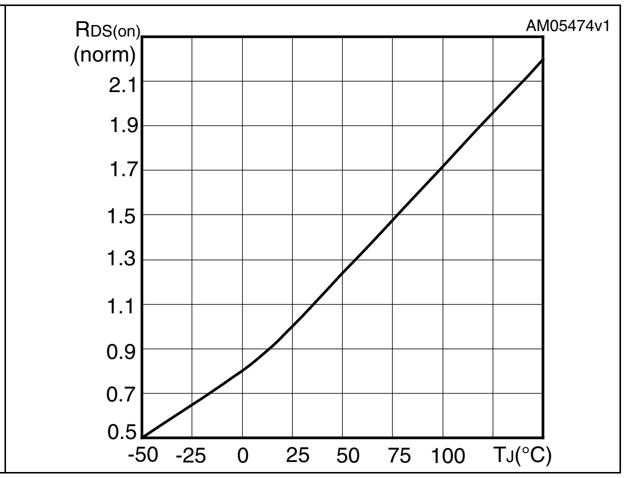


Figure 16. Source-drain diode forward characteristics

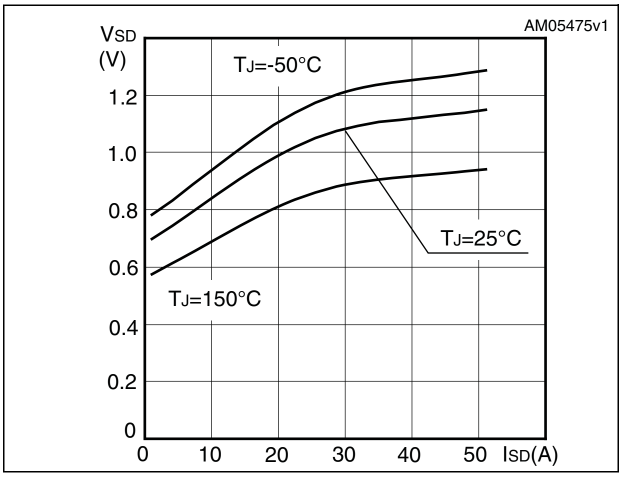


Figure 17. Normalized B_{VDSS} vs temperature

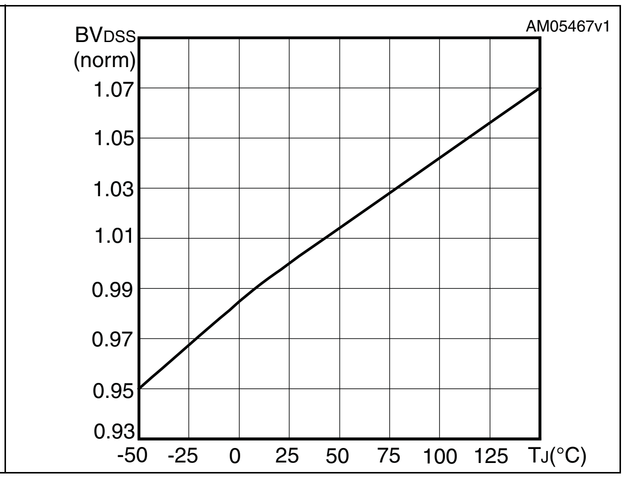
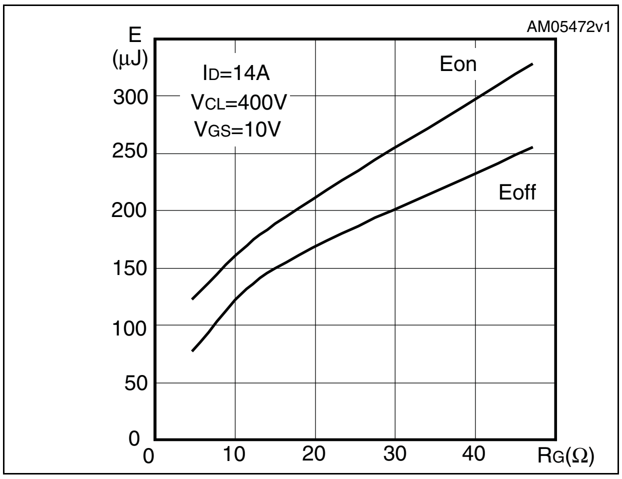


Figure 18. Switching losses vs gate resistance (1)



1. Eon including reverse recovery of a SiC diode

3 Test circuits

Figure 19. Switching times test circuit for resistive load

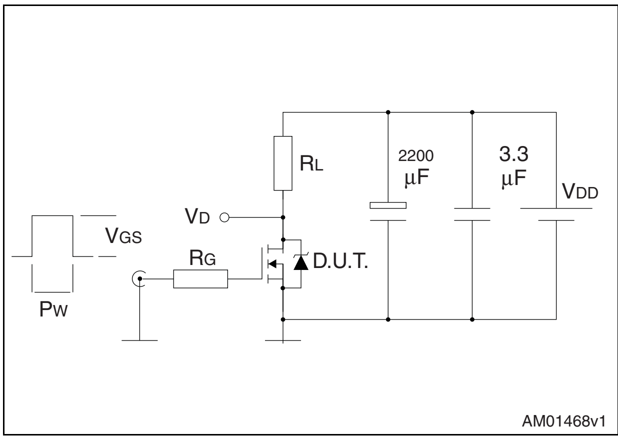


Figure 20. Gate charge test circuit

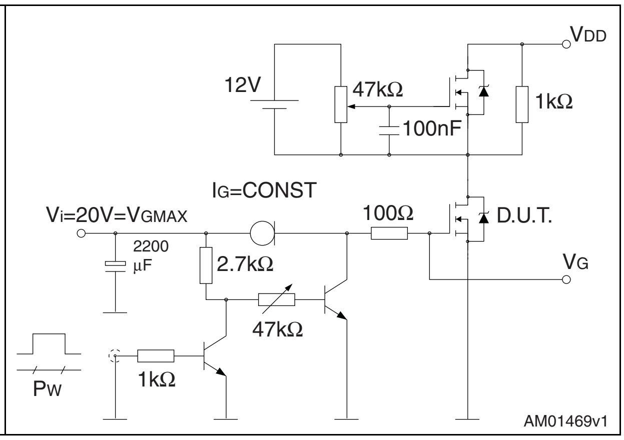


Figure 21. Test circuit for inductive load switching and diode recovery times

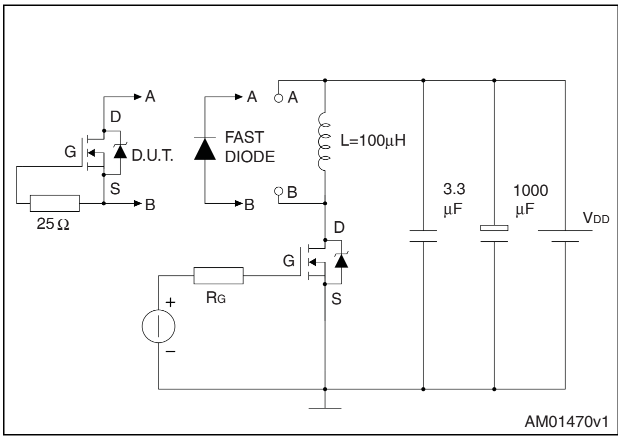


Figure 22. Unclamped inductive load test circuit

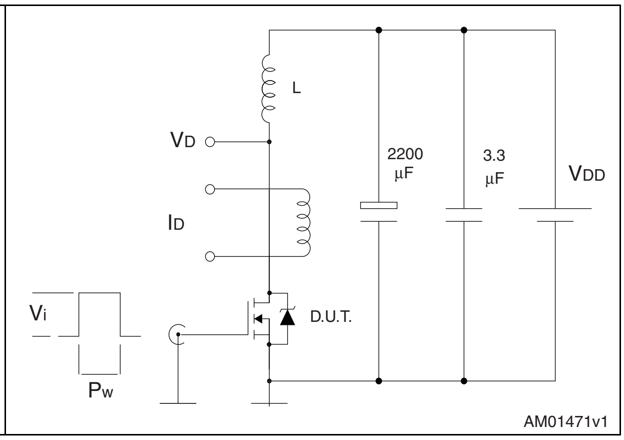


Figure 23. Unclamped inductive waveform

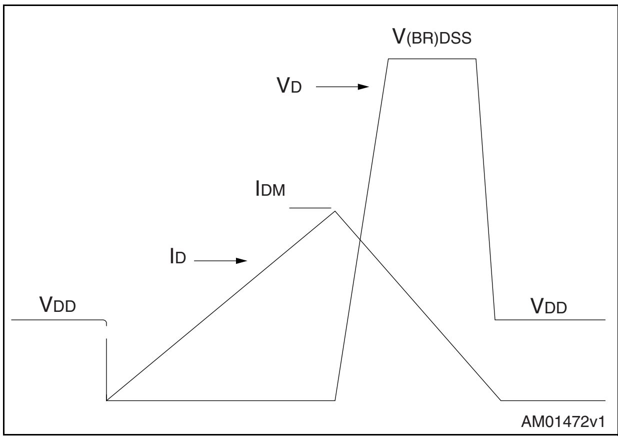
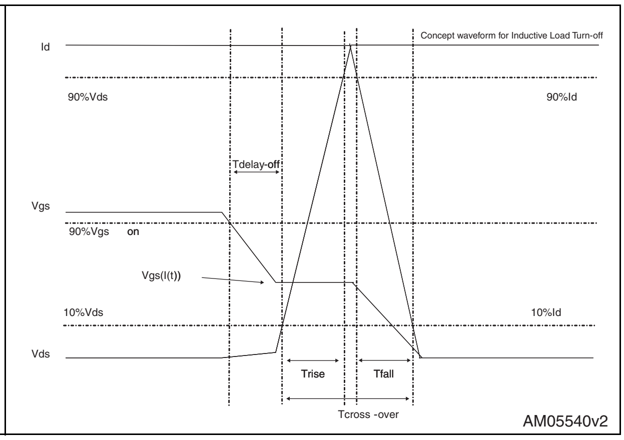


Figure 24. Switching time waveform



4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACKm is an ST trademark.

Table 8. D^2PAK (TO-263) mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
A1	0.03		0.23
b	0.70		0.93
b2	1.14		1.70
c	0.45		0.60
c2	1.23		1.36
D	8.95		9.35
D1	7.50		
E	10		10.40
E1	8.50		
e		2.54	
e1	4.88		5.28
H	15		15.85
J1	2.49		2.69
L	2.29		2.79
L1	1.27		1.40
L2	1.30		1.75
R		0.4	
V2	0°		8°

Figure 25. D²PAK (TO-263) drawing

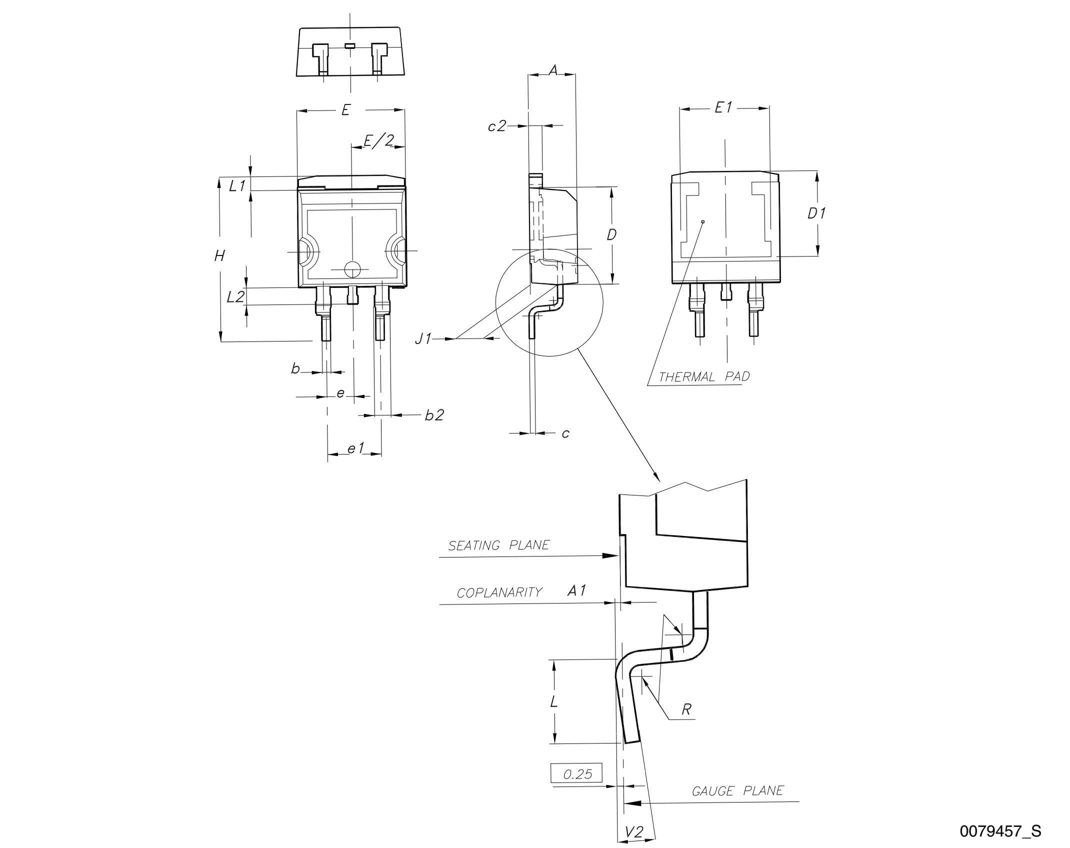
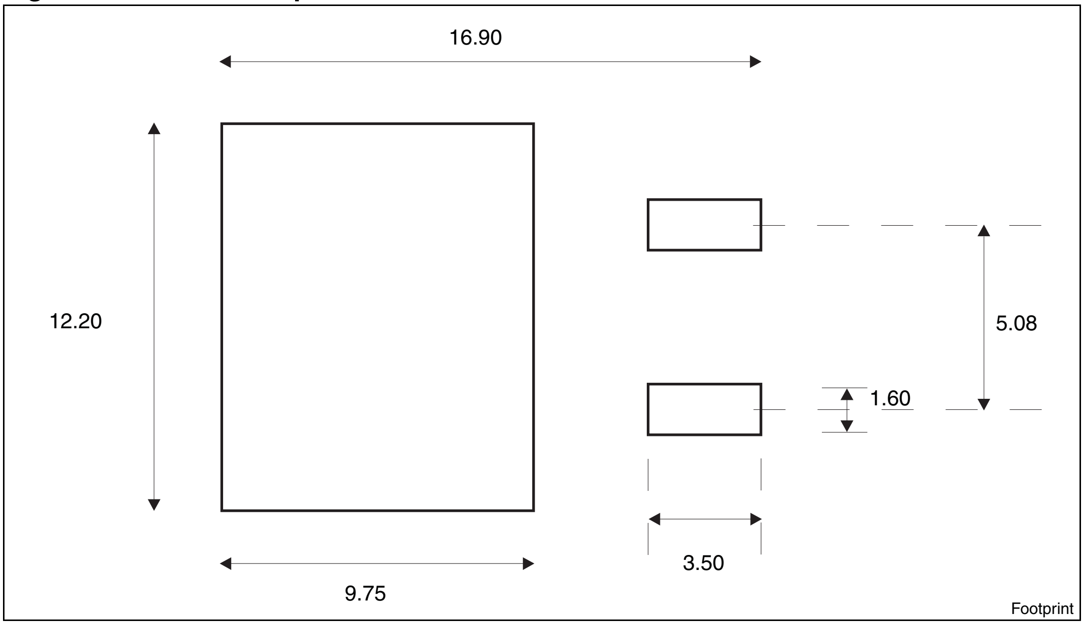


Figure 26. D²PAK footprint[(a)]



a. All dimensions are in millimeters

Table 9. TO-220FP mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.4		4.6
B	2.5		2.7
D	2.5		2.75
E	0.45		0.7
F	0.75		1
F1	1.15		1.70
F2	1.15		1.70
G	4.95		5.2
G1	2.4		2.7
H	10		10.4
L2		16	
L3	28.6		30.6
L4	9.8		10.6
L5	2.9		3.6
L6	15.9		16.4
L7	9		9.3
Dia	3		3.2

Figure 27. TO-220FP drawing

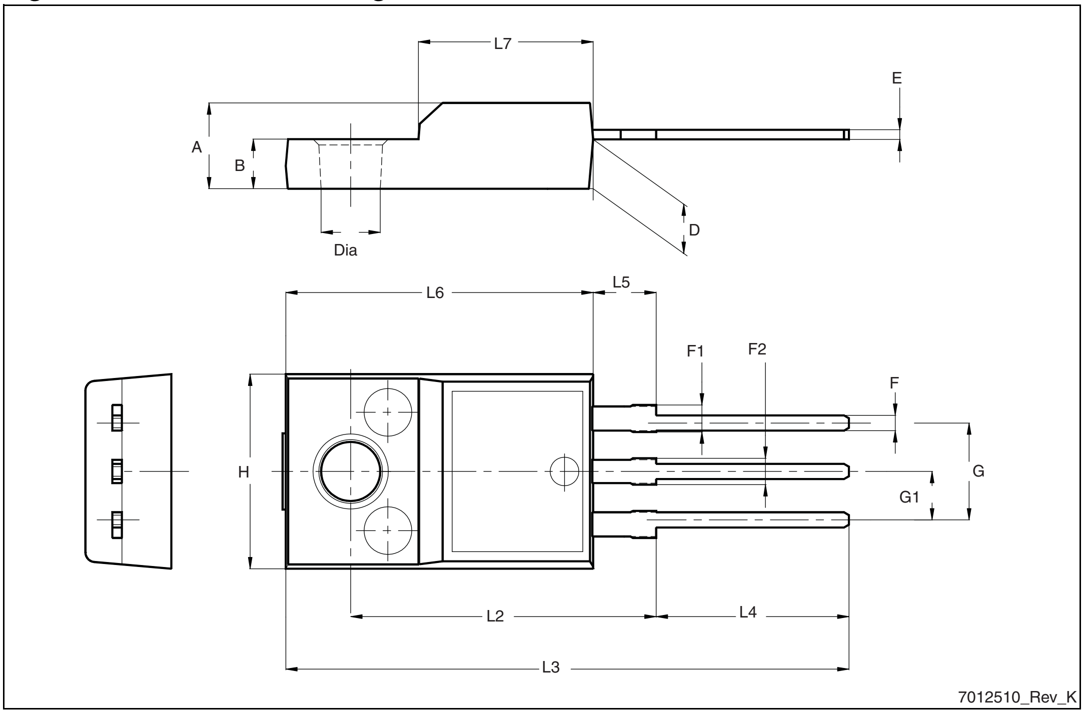


Table 10. I²PAK (TO-262) mechanical data

DIM.	mm.		
	min.	typ	max.
A	4.40		4.60
A1	2.40		2.72
b	0.61		0.88
b1	1.14		1.70
c	0.49		0.70
c2	1.23		1.32
D	8.95		9.35
e	2.40		2.70
e1	4.95		5.15
E	10		10.40
L	13		14
L1	3.50		3.93
L2	1.27		1.40

Figure 28. I²PAK (TO-262) drawing

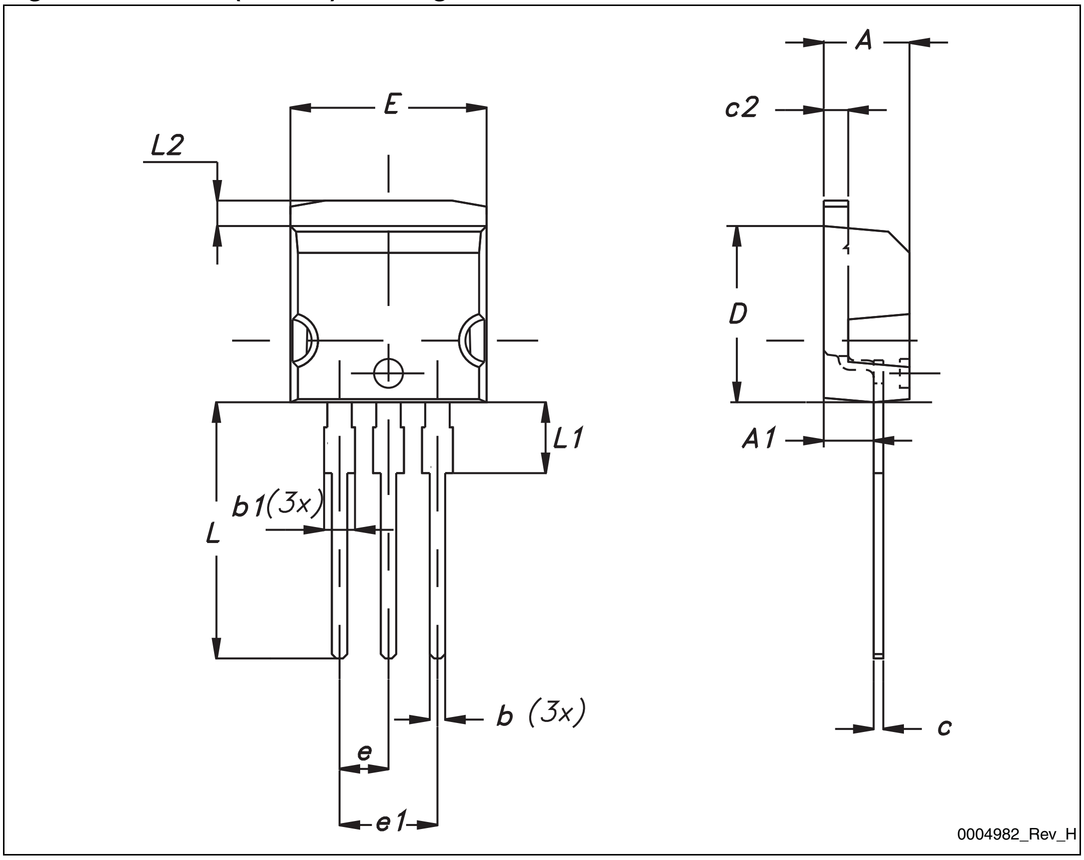


Table 11. TO-220 type A mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.48		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
∅P	3.75		3.85
Q	2.65		2.95

Figure 29. TO-220 type A drawing

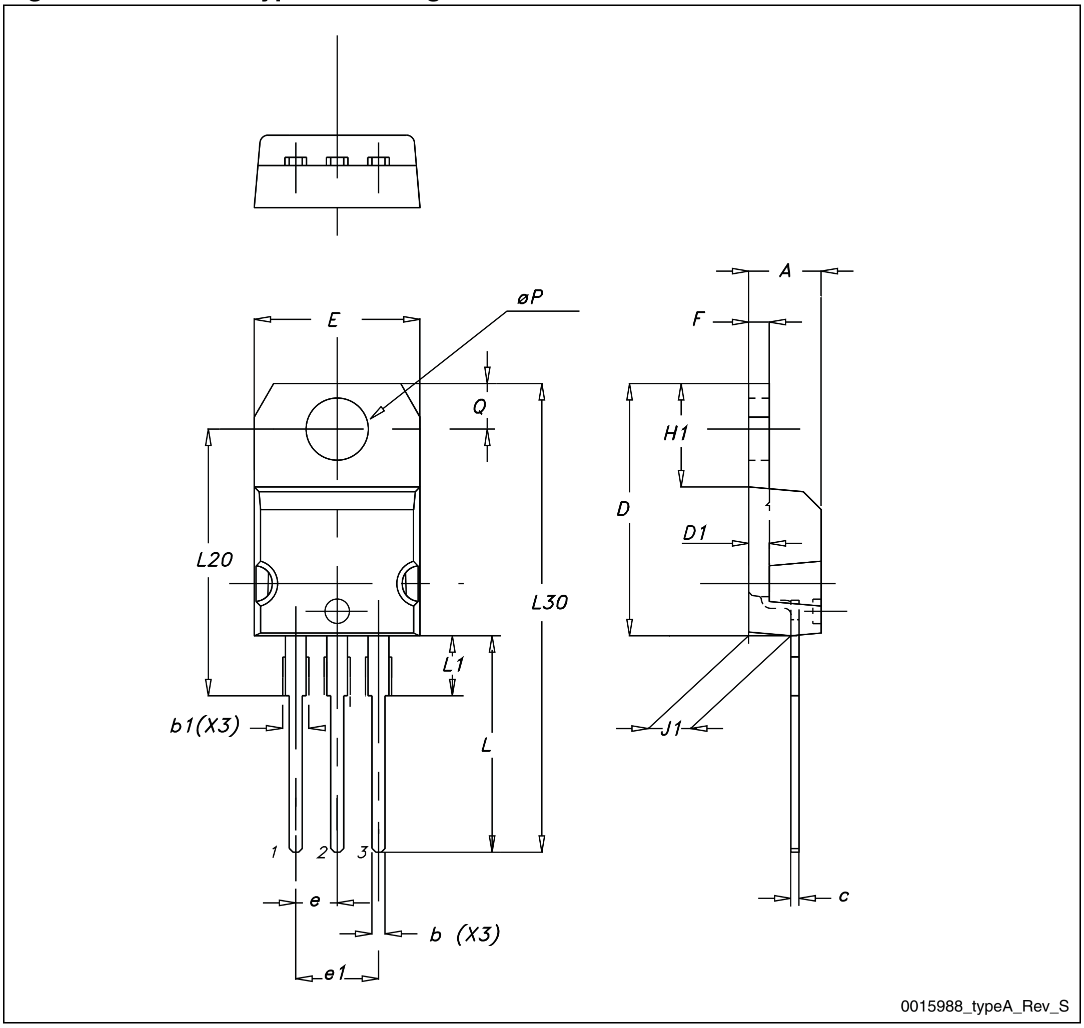
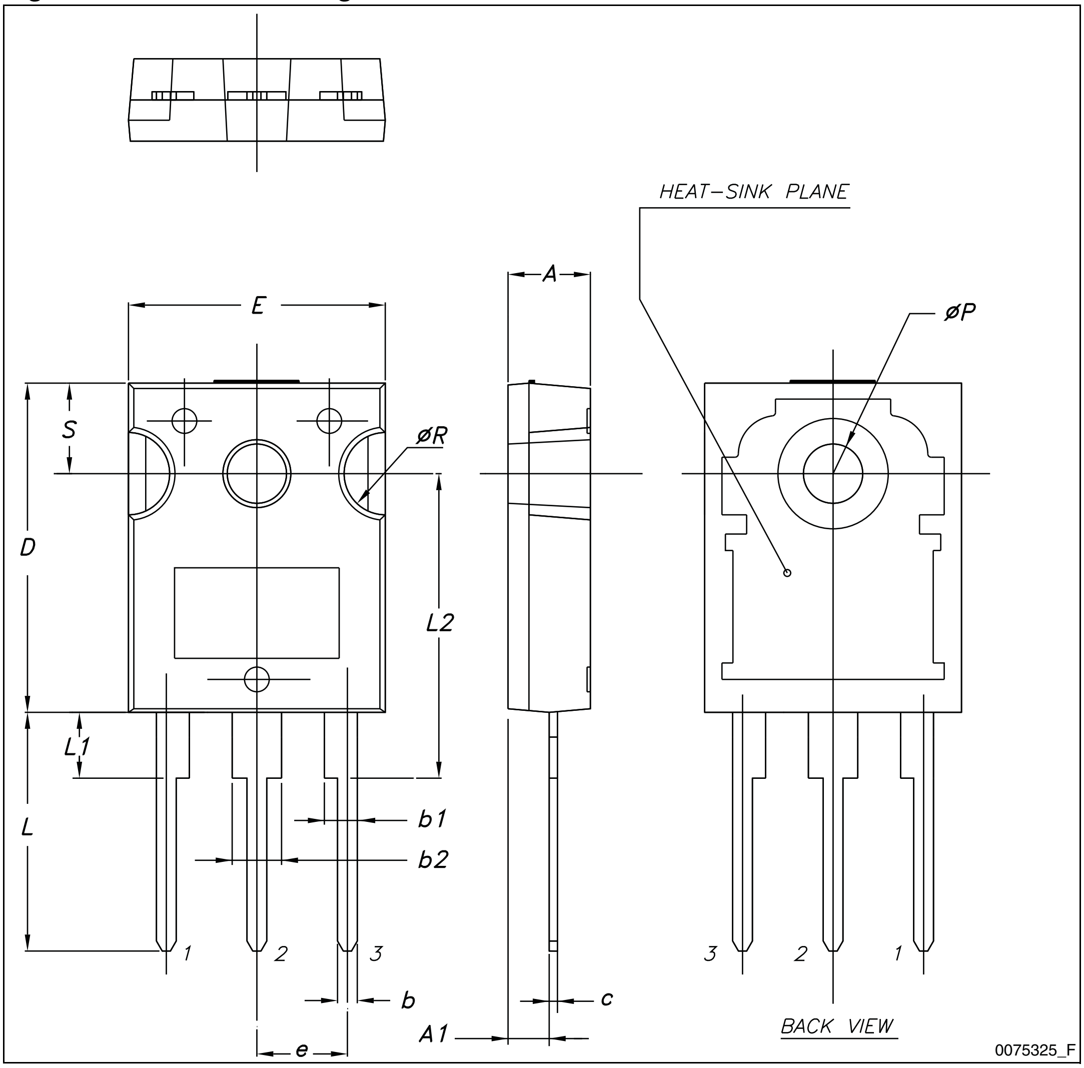


Table 12. TO-247 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.85		5.15
A1	2.20		2.60
b	1.0		1.40
b1	2.0		2.40
b2	3.0		3.40
c	0.40		0.80
D	19.85		20.15
E	15.45		15.75
e		5.45	
L	14.20		14.80
L1	3.70		4.30
L2		18.50	
∅P	3.55		3.65
∅R	4.50		5.50
S		5.50	

Figure 30. TO-247 drawing



5 Packaging mechanical data

Table 13. D^2PAK (TO-263) tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base qty		1000
P2	1.9	2.1	Bulk qty		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

Figure 31. Tape

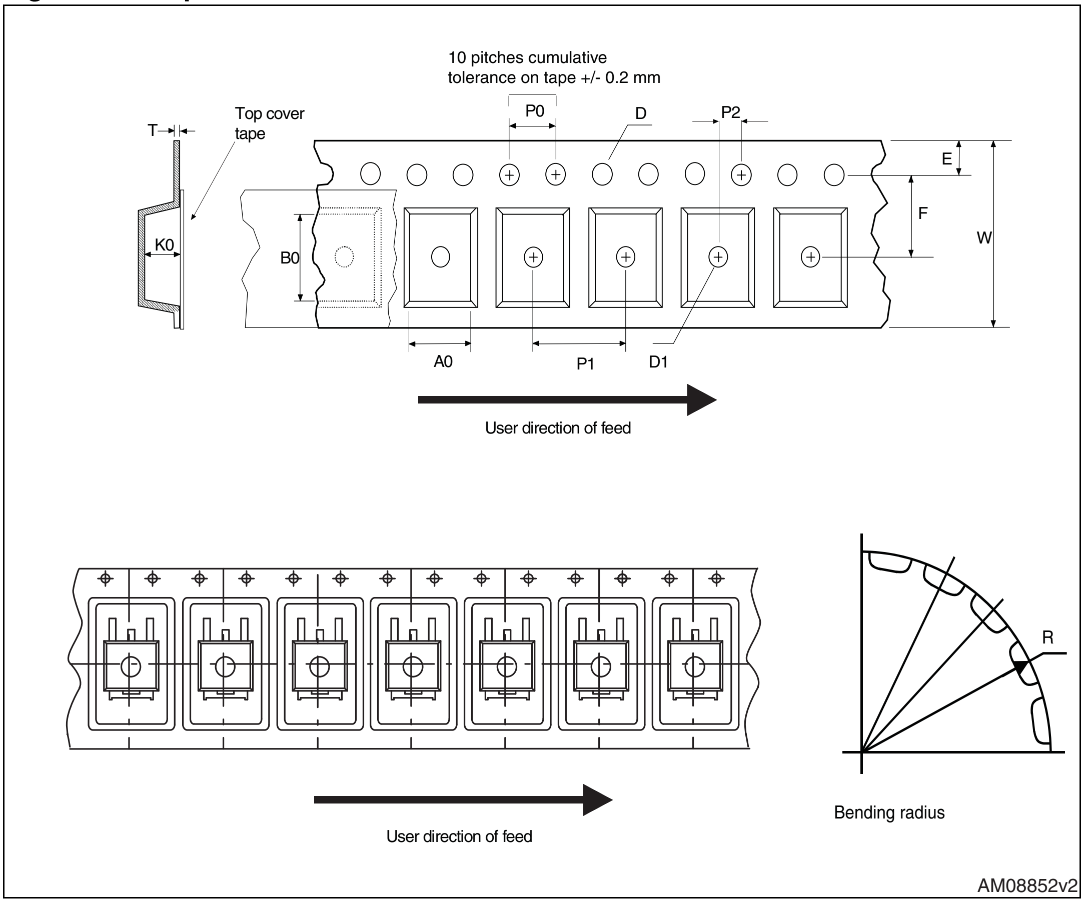
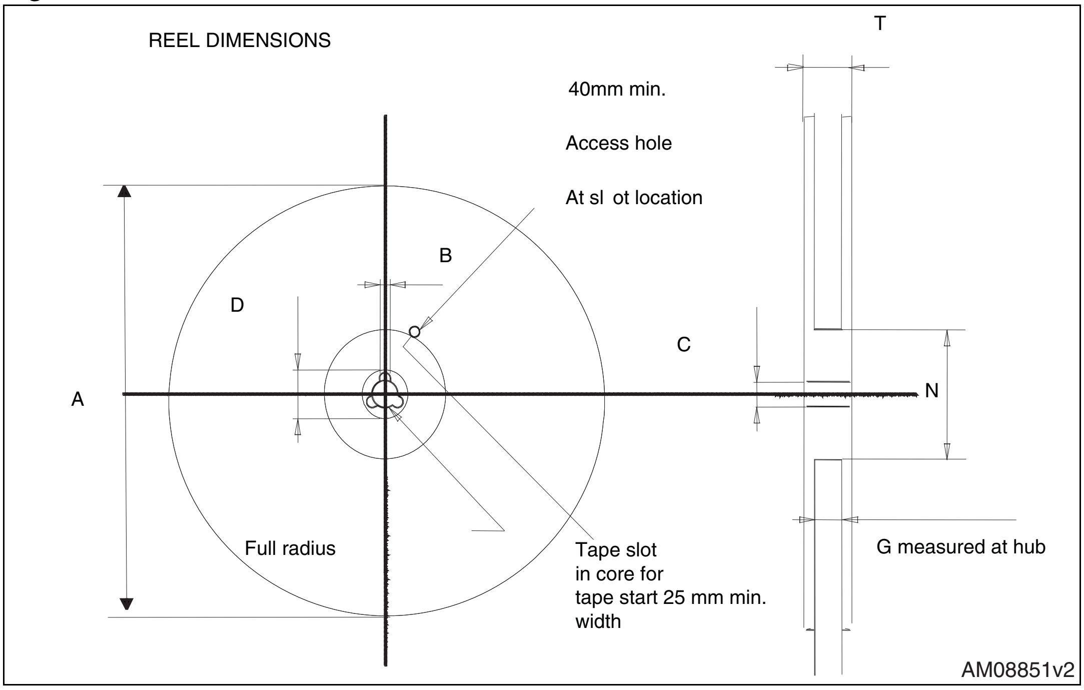


Figure 32. Reel



6 Revision history

Table 14. Document revision history

Date	Revision	Changes
16-Jan-2009	1	First release
21-Sep-2009	2	Document status promoted from preliminary data to datasheet.
22-Sep-2011	3	$C_{o(er)}$ and $C_{o(tr)}$ values changed in *Table 5: Dynamic* *Table 6: Switching times* parameters updates *Figure 24: Switching time waveform* has been corrected Minor text changes *Section 4: Package mechanical data* has been modified. Added: – *Table 8: D²PAK (TO-263) mechanical data*, *Figure 25: D²PAK (TO-263) drawing* and *Figure 26: D²PAK footprint*; – *Table 9: TO-220FP mechanical data*,and *Figure 27: TO-220FP drawing*; – *Table 10: I²PAK (TO-262) mechanical data*,and *Figure 28: I²PAK (TO-262) drawing*; – *Table 11: TO-220 type A mechanical data*,and *Figure 29: TO-220 type A drawing*; – *Table 12: TO-247 mechanical data*,and *Figure 30: TO-247 drawing*; *Section 5: Packaging mechanical data* has been modified. Added: – *Table 13: D²PAK (TO-263) tape and reel mechanical data*, *Figure 31: Tape* and *Figure 32: Reel*;